

Cesium lead iodide solar cell controlled by annealing temperature

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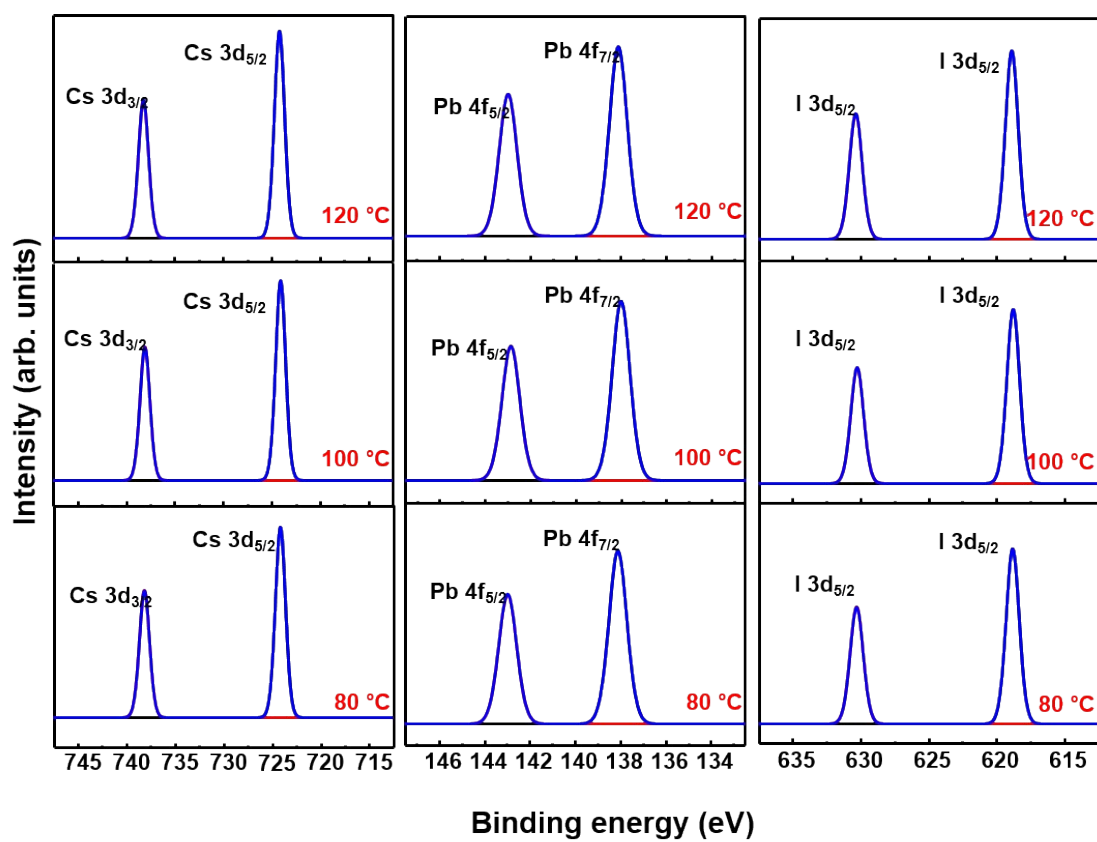


Figure S1 X-ray photoelectron spectroscopy (XPS) spectra of CsPbI₃ film.

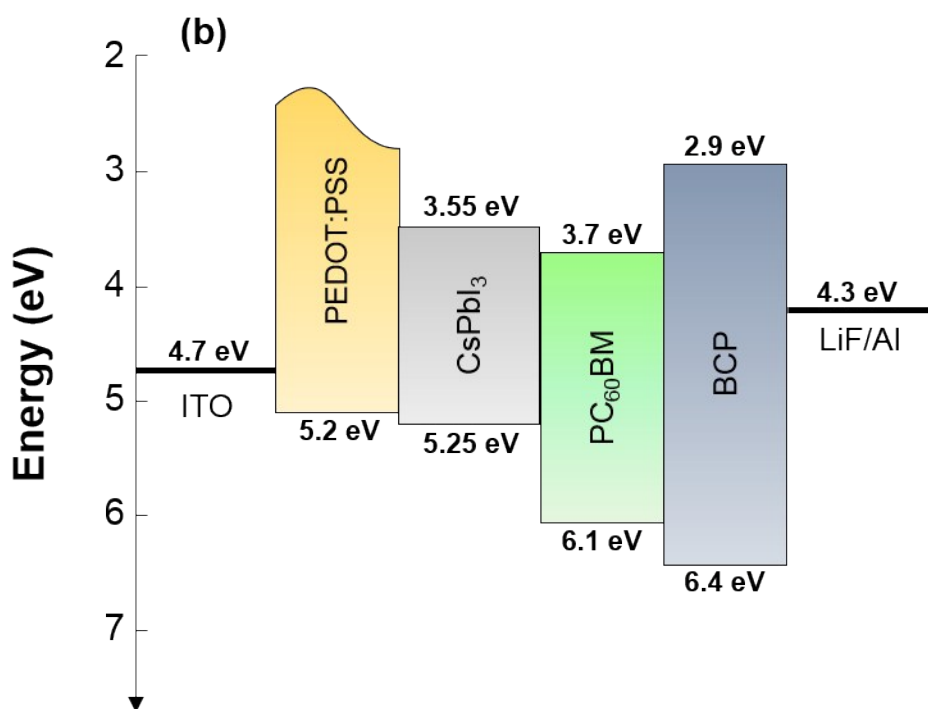
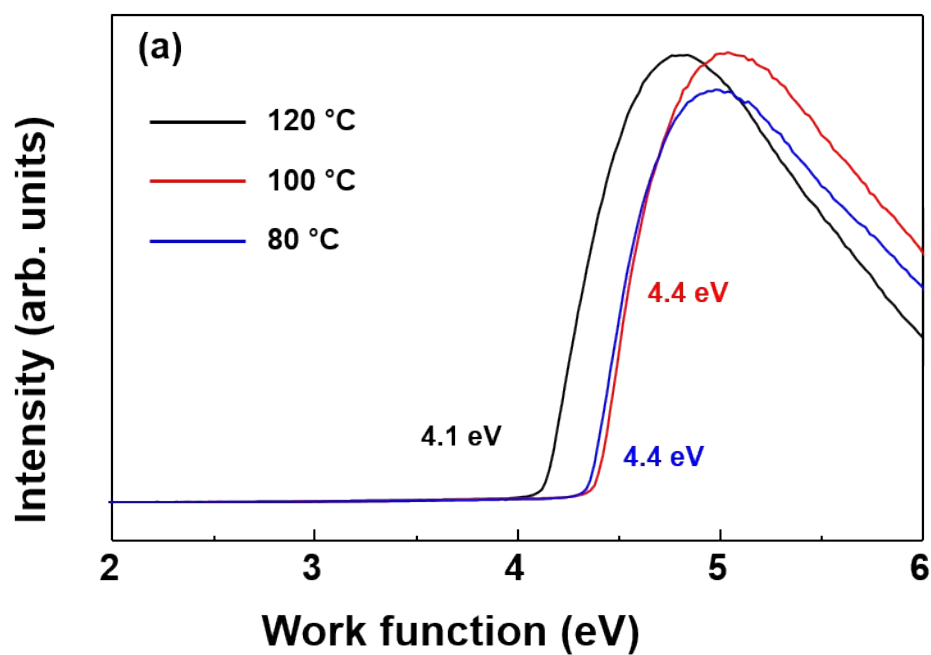


Figure S2 Work function of temperature control from 80 °C to 120 °C and energy band diagram of PSC.